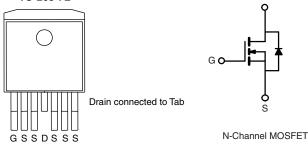


Automotive N-Channel 40 V (D-S) 175 °C MOSFET

D

| PRODUCT SUMMARY | | | | | |
|--|--------|--|--|--|--|
| V _{DS} (V) | 40 | | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$ | 0.0011 | | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 V$ | 0.0013 | | | | |
| I _D (A) | 200 | | | | |
| Configuration | Single | | | | |

TO-263-7L



FEATURES

- TrenchFET[®] Power MOSFET
- Package with Low Thermal Resistance
- 100 % R_q and UIS Tested
- AEC-Q101 Qualified^d
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



| ORDERING INFORMATION | | | | |
|---------------------------------|--------------------|--|--|--|
| Package | TO-263-7L | | | |
| Lead (Pb)-free and Halogen-free | SQM200N04-1m1L-GE3 | | | |

| ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted) | | | | | | |
|---|-------------------------|-----------------------------------|---------------|------|--|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | | |
| Drain-Source Voltage | | V _{DS} | 40 | | | |
| Gate-Source Voltage | | V _{GS} | ± 20 | V | | |
| Continuous Drain Current ^a | T _C = 25 °C | 1 | 200 | | | |
| Continuous Drain Current ^a | T _C = 125 °C | I _D | 200 | | | |
| Continuous Source Current (Diode Conduction) | I _S | 200 | А | | | |
| Pulsed Drain Current ^b | | I _{DM} | 600 | | | |
| Single Pulse Avalanche Current | L = 0.1 mH | I _{AS} | 100 | | | |
| Single Pulse Avalanche Energy | L = 0.1 mH | E _{AS} | 500 | mJ | | |
| Maximum Power Dissipation ^b | T _C = 25 °C | P | 375 | W | | |
| | T _C = 125 °C | P _D | 125 | vv | | |
| Operating Junction and Storage Temperature F | lange | T _J , T _{stg} | - 55 to + 175 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|----------------------------|------------------------|-------------------|-------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Junction-to-Ambient | PCB Mount ^c | R _{thJA} | 40 | °C/W | |
| Junction-to-Case (Drain) | | R _{thJC} | 0.4 | 0/10 | |

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.

SQM200N04-1m1L



Vishay Siliconix

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT | |
|---|--------------------------|---|---|------|--------|--------|------|--|
| Static | | • | | | | | • | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 V, I_D = 250 \mu A$ | | 40 | - | - | V | |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = | = V _{GS} , I _D = 250 μΑ | 1.5 | 2.0 | 2.5 | V | |
| Gate-Source Leakage | I _{GSS} | V _{DS} = | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | - | ± 100 | nA | |
| | | $V_{GS} = 0 V$ | V _{DS} = 40 V | - | - | 1 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{GS} = 0 V$ | V _{DS} = 40 V, T _J = 125 °C | - | - | 50 | μA | |
| | | $V_{GS} = 0 V$ | V _{DS} = 40 V, T _J = 175 °C | - | - | 500 | | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V | $V_{DS} \ge 5 V$ | 200 | - | - | Α | |
| | | $V_{GS} = 10 V$ | I _D = 30 A | - | 0.0008 | 0.0011 | Ω | |
| | | V _{GS} = 10 V | I _D = 30 A, T _J = 125 °C | - | - | 0.0019 | | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = 10 V | I _D = 30 A, T _J = 175 °C | - | - | 0.0023 | | |
| | | V _{GS} = 4.5 V | I _D = 20 A | - | 0.0009 | 0.0013 | | |
| Forward Transconductanceb | 9 _{fs} | V _{DS} = 15 V, I _D = 30 A | | - | 219 | - | S | |
| Dynamic ^b | • | | | | • | | • | |
| Input Capacitance | C _{iss} | | V _{DS} = 25 V, f = 1 MHz | - | 16 524 | 20 655 | pF | |
| Output Capacitance | C _{oss} | $V_{GS} = 0 V$ | | - | 2060 | 2575 | | |
| Reverse Transfer Capacitance | C _{rss} | 1 | | - | 484 | 605 | | |
| Total Gate Charge ^c | Qg | | | - | 275 | 413 | nC | |
| Gate-Source Charge ^c | Q _{gs} | $V_{GS} = 10 V$ | $V_{DS} = 20 \text{ V}, I_D = 20 \text{ A}$ | - | 56.6 | - | | |
| Gate-Drain Charge ^c | Q _{gd} | 1 | | - | 45.4 | - | | |
| Gate Resistance | Rg | f = 1 MHz | | 4.2 | 8.5 | 12.8 | Ω | |
| Turn-On Delay Time ^c | t _{d(on)} | $V_{DD} = 20 \text{ V}, \text{ R}_{\text{L}} = 1 \Omega$ $\text{I}_{\text{D}} \cong 20 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$ | | - | 13 | 20 | | |
| Rise Time ^c | t _r | | | - | 12 | 18 | ns | |
| Turn-Off Delay Time ^c | t _{d(off)} | | | - | 443 | 665 | | |
| Fall Time ^c | t _f | | | - | 126 | 189 | | |
| Source-Drain Diode Ratings and Char | acteristics ^b | • | | | | | | |
| Pulsed Current ^a | I _{SM} | | | - | - | 600 | Α | |
| Forward Voltage | V _{SD} | I _F = | = 60 A, V _{GS} = 0 V | - | 0.8 | 1.5 | V | |
| | | | | | | | | |

Notes

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

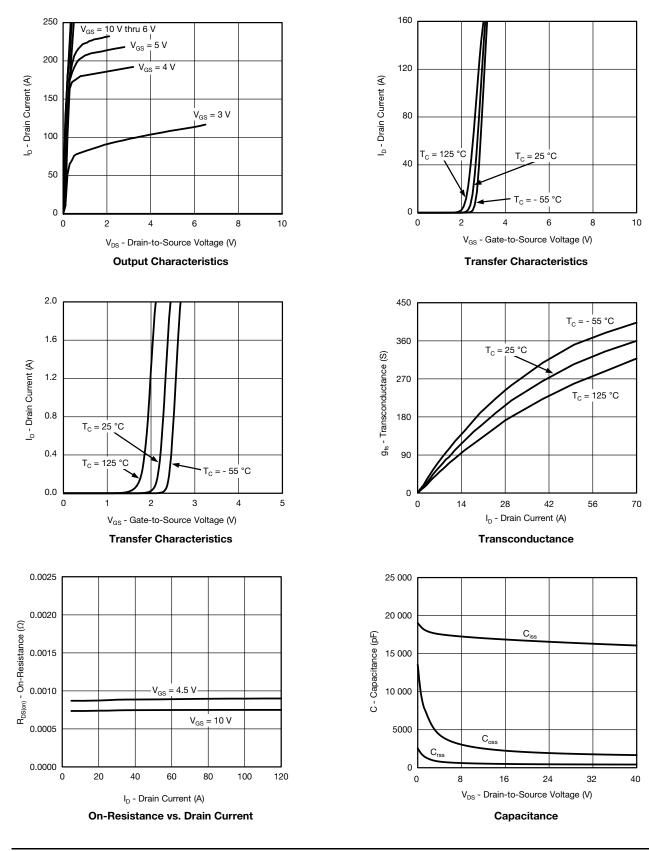
b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

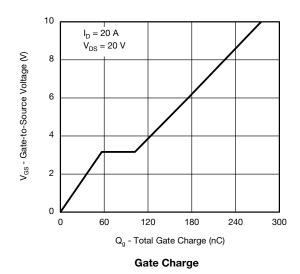


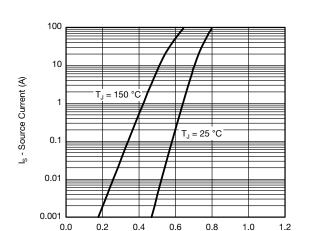
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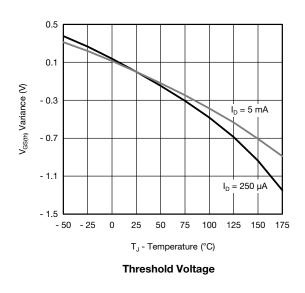


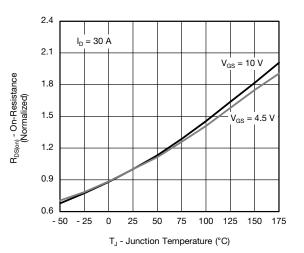
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



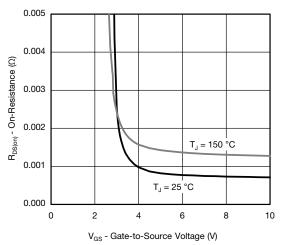


V_{SD} - Source-to-Drain Voltage (V) Source Drain Diode Forward Voltage

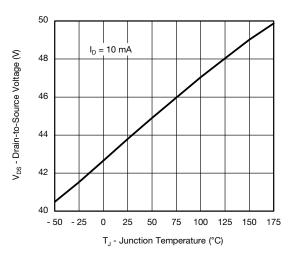




On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature

S12-2164-Rev. A, 24-Sep-12

4

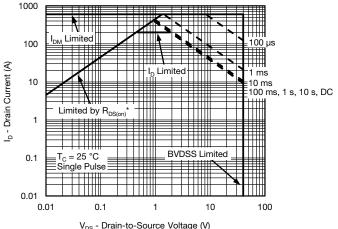
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SQM200N04-1m1L

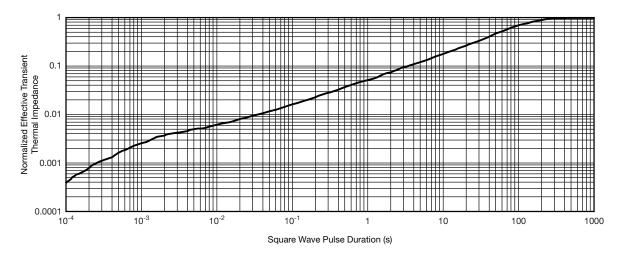
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



 V_{DS} - Drain-to-Source Voltage (V) * V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

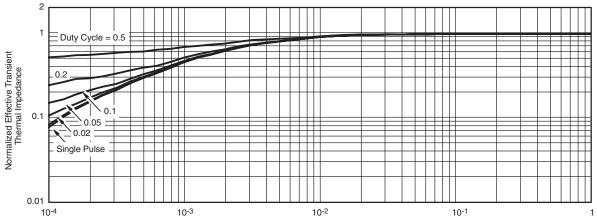




Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Case

Note

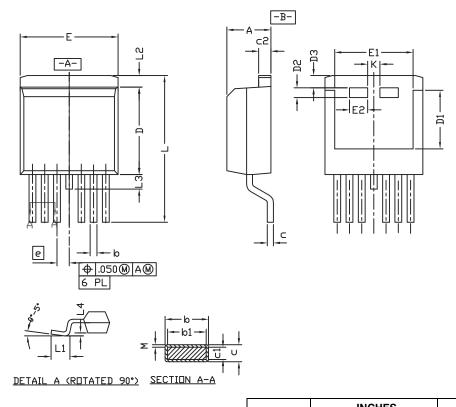
- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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D²PAK (TO-263-7L) Case Outline



Notes

- 1. Plane B includes maximum features of heat sink tab and plastic
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils
- 3. Pin to pin coplanarity max. 4 mils
- 4. Lead thickness 25 mils
- 5. For SUM part numbers lead thickness is 24 mils to 29 mils
- 6. For reference only
- 7. Use inches as the primary measurement
- 8. This feature is only for SUM

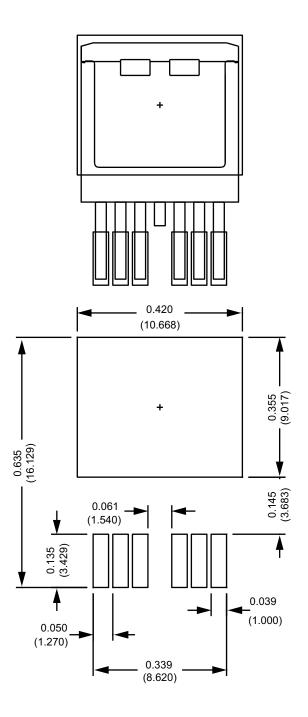
| | INCHES | | MILLIMETERS | | |
|--|-----------|-------|-------------|--------|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | |
| А | 0.160 | 0.190 | 4.064 | 4.826 | |
| b | 0.020 | 0.039 | 0.508 | 0.990 | |
| b1 | 0.020 | 0.035 | 0.508 | 0.889 | |
| c* SUB | 0.012 | 0.018 | 0.305 | 0.457 | |
| c* SUM | 0.022 | 0.028 | 0.559 | 0.711 | |
| c1 | 0.018 | 0.025 | 0.457 | 0.635 | |
| c2 | 0.045 | 0.055 | 1.143 | 1.397 | |
| D | 0.340 | 0.380 | 8.636 | 9.652 | |
| D1 | 0.260 | 0.280 | 6.604 | 7.112 | |
| D2 | 0.046 | 0.050 | 1.168 | 1.270 | |
| D3 | 0.045 | 0.055 | 1.143 | 1.397 | |
| E | 0.380 | 0.410 | 9.652 | 10.414 | |
| E1 | 0.245 | - | 6.223 | - | |
| E2 | 0.072 | 0.078 | 1.829 | 1.981 | |
| е | 0.050 BSC | | 1.27 BSC | | |
| K | 0.045 | 0.055 | 1.143 | 1.397 | |
| L | 0.575 | 0.625 | 14.605 | 15.875 | |
| L1 | 0.090 | 0.110 | 2.286 | 2.794 | |
| L2 | 0.040 | 0.055 | 1.016 | 1.397 | |
| L3 | 0.050 | 0.070 | 1.270 | 1.778 | |
| L4 | 0.010 BSC | | 0.254 BSC | | |
| М | - | 0.002 | - | 0.050 | |
| ECN: T22-0410-Rev. D, 19-Sep-2022 DWG: 6006 | | | | | |

Document Number: 63782





Recommended Land Pattern D²PAK (TO-263-7L)



Revision: 23-Jul-2020



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